

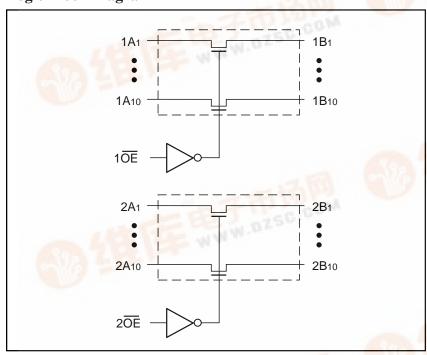
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PI3B16210 PI3B162210 (25Ω)

## **Product Features**

- · Near-zero propagation delay
- $5\Omega$  or  $25\Omega$  switches connect inputs to outputs
- Fair Switching Speed 4.5ns max.
- 32X384 function with flow through pinout make board layout easier
- Permits Hot Insertion.
- Vcc Operating Range: 3.0V to 3.6V
- Industrial operating temperature: -40°C to +85°C
- Packages available:
  - 48-pin 150-mil wide plastic QSOP (B)
  - 48-pin 240-mil wide plastic TSSOP (A)
  - 48-pin 300-mil wide plastic SSOP (V)

## Logic Block Diagram



## Truth Table<sup>(1)</sup>

Inp	outs	Inputs/Outputs				
1 <del>OE</del> 2 <del>OE</del>		1A,1B	2A,2B			
L	L	1A = 1B	2A = 2B			
L	Н	1A = 1B	Z			
Н	L	Z	2A = 2B			
μH	Н	Z	Z			

# High Voltage Level L = Low Voltage Level Hi-Z = High Impedance

## 3.3V, Hot Insertion 20-Bit, 2-Port BusSwitch

## **Product Description**

Pericom Semiconductor's PI3B series of BusSwitch circuits are produced in the Company's advanced 0.35 micron CMOS technology, achieving industry leading speed.

The PI3B16210 is configured as 3.3 volt 20-bit, 2-port bus switches designed with a low ON resistance ( $5\Omega$ ) allowing inputs to be connected directly to outputs. The bus switch creates no additional propagational delay or additional ground bounce noise. The switches are turned ON by the Bus Enable ( $x\overline{OE}$ ) input signal.

The PI3B162210 device has a built-in 25-ohm series resistor to reduce noise resulting from reflections, thus eliminating the need for an external terminating resistor.

## **Product Pin Configuration**

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	ис Ц	1	$\overline{\mathbf{U}}$	48	10E
	1A1 [	2		47	20E
	1A1 L	3		46	1B <sub>1</sub>
	1A2 L 1A3 [	-		45	1B <sub>2</sub>
	1A4 [			44	1B3
	1A5 [			43	1B4
	1A6 [	7	48-Pin	42	1B5
	GND [		40-1 III	41	GND
	1A7 🗆			40	1B6
	1A8 🛘			39	☐ 1B <sub>7</sub>
	1A9 🛚	11		38	☐ 1B8
	1A10 □	12		37	☐ 1B9
	2A1 🛚	13		36	☐ 1B10
	2A2 🛚	14		35	2B <sub>1</sub>
	Vcc 🛚	15		34	☐ 2B2
	2A3 🗆	16		33	☐ 2B3
	GND [	17		32	GND
	2A4 🛚	18		31	□ 2B4
	2A5 🛚	19		30	<b>⊒</b> 2B₅
	2A6 🛚	20		29	□ 2B6
	2A7 🛭	21		28	□ 2B7
	2A8 [	22		27	□ 2B8
	2A9 🛭	23		26	<b>2B</b> 9
	2A10 🗖	24		25	2B10
					1

## **Product Pin Description**

Pin Name	Description
1 <del>OE</del> , 2 <del>OE</del>	Bus Enable Inputs (Active LOW)
1A1-1A10, 2A1-2A10	Bus A
1B1 - 1B10, 2B1 - 2B10	Bus B



## **Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	65°C to +150°C
Ambient Temperature with Power Applied	0°C to +85°C
Supply Voltage Range	0.5V to +4.6V
DC Input Voltage	0.5V to +4.6V
DC Output Current	120 mA
Power Dissipation	0.5W

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

## **DC Electrical Characteristics** (Over the Operating Range, $TA = -40^{\circ}C$ to $+85^{\circ}C$ , VCC = 3.0V to 3.6V)

Parameters	Description	Test Conditions <sup>(1)</sup>	Test Conditions <sup>(1)</sup>			Max.	Units
VIH	Input HIGH Voltage	Guaranteed Logic HIGH Level	1	2.0	_	_	V
VIL	Input LOW Voltage	Guaranteed Logic LOW Level		-0.5	_	0.8	V
Iı	Input Current	Vcc = Max. Vin = Vcc or GN	D	_	_	±1	μΑ
		$V_{CC} = 0V$ , $V_{IN} = V_{CC}$		_	_	±1	μΑ
Іохн	High Impedance Output Current	$0 \le A, B \le V_{CC}$	_	_	10	μΑ	
Vik	Clamp Diode Voltage	$V_{CC} = Min, I_{IN} = -18mA$		_	-0.7	-1.2	V
Ron	Switch On Resistance <sup>(3)</sup>	$V_{CC} = 3V$ , $V_{IN} = 0.0V$ ,	16210	_	5	8	Ω
		Ion = 24  mA, 64mA	162210	20	28	40	
		$V_{CC} = 3V, V_{IN} = 2.4V,$	16210		_	15	Ω
		Ion = 15mA	162210	20	35	48	

### Capacitance ( $TA = 25^{\circ}C$ , f = 1 MHz)

Parameters <sup>(4)</sup>	Description	Test Conditions	Тур	Units
CIN	Input Capacitance	$V_{IN} = 0V$	3.0	
Coff	A/B Capacitance, Switch OFF	$V_{IN} = 0V$	8.5	pF
Con	A/B Capacitance, Switch ON	$V_{IN} = 5V$	17.0	

#### **Notes:**

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 3.3V, TA = 25°C ambient and maximum loading.
- 3. Measured by the voltage drop between A and B pin at indicated current through the switch. ON resistance is determined by the lower of the voltages on the two (A,B) pins.
- 4. This parameter is determined by device characterization but is not production tested.



## **Power Supply Characteristics**

Parameters	Description	Test Conditions <sup>(1)</sup>			Typ <sup>(2)</sup>	Max.	Units
Icc	Quiescent Power Supply Current	Vcc = Max.	$V_{IN} = GND \text{ or } V_{CC}$			10	μА
ΔΙcc	Supply Current per Input @ TTL HIGH	Vcc = Max.	$V_{IN} = 3.0V^{(3)}$			750	μА
ICCD	Supply Current per Input per MHz <sup>(4)</sup>	Vcc = Max.  A and B Pins Open  BE = GND  Control Input Toggling  50% Duty Cycle				0.25	mA/ MHz

#### **Notes:**

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- 2. Typical values are at Vcc = 3.3V,  $+25^{\circ}C$  ambient.
- 3. Per TTL driven input (control inputs only); A and B pins do not contribute to Icc.
- 4. This current applies to the control inputs only and represent the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is not tested, but is guaranteed by design.

## **Switching Characteristics over Operating Range**

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Parameters	Description	Conditions	1)	Min	Max	Units
tPLH	Propagation Delay <sup>(2,3)</sup>	$C_L = 50pF$	16210		0.25	
tPHL	Ax to Bx, Bx to Ax	$R_L = 500\Omega$	162210		1.25	
tPZH	Bus Enable Time	$C_r = 50 \text{pF}$		1	4.5	ns
tPZL	BE to Ax or Bx	$C_L = 50 pF,$ $R_L = 500 \Omega,$				
tPHZ	Bus Disable Time	$R = 500\Omega$		1	5.0	
tPLZ	BE to Ax or Bx					

#### Notes:

- 1. See test circuit and wave forms.
- 2. This parameter is guaranteed but not tested on Propagation Delays.
- 3. The bus switch contributes no propagational delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns for 50pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.